onsemi

Complementary Silicon Power Transistors

TIP3055 (NPN), TIP2955 (PNP)

Designed for general-purpose switching and amplifier applications.

Features

DC Current Gain –

 $h_{FE} = 20 - 70 @ I_C$

= 4.0 Adc

• Collector-Emitter Saturation Voltage – V_{CE(sat)} = 1.1 Vdc (Max) @ I_C

 $= 4.0 \,\mathrm{Adc}$

- Excellent Safe Operating Area
- These are Pb-Free Devices*

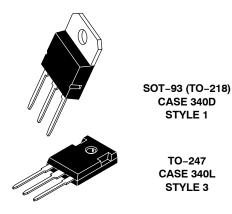
MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V _{CEO}	Collector – Emitter Voltage	60	Vdc
V _{CER}	Collector – Emitter Voltage	70	Vdc
V _{CB}	Collector – Base Voltage	100	Vdc
V _{EB}	Emitter – Base Voltage	7.0	Vdc
Ι _C	Collector Current – Continuous	15	Adc
Ι _Β	Base Current	7.0	Adc
P _D	Total Power Dissipation @ T _C = 25°C Derate above 25°C	90 0.72	W W/°C
T _J , T _{stg}	Operating and Storage Junction Temperature Range	−65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

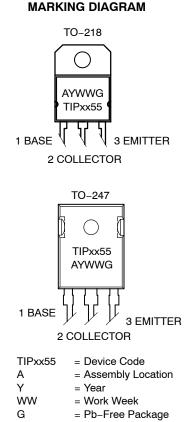
THERMAL CHARACTERISTICS

Symbol	Symbol Characteristic		Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	1.39	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	35.7	°C/W



NOTE: Effective June 2012 this device will be available only in the TO-247 package. Reference FPCN# 16827.

15 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 60 VOLTS, 90 WATTS



ORDERING INFORMATION

*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, <u>SOLDERRM/D</u>.

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Characteristic	Min	Max	Unit	
OFF CHARAC	DFF CHARACTERISTICS				
V _{CEO(sus)}	Collector-Emitter Sustaining Voltage (Note 1) $(I_C = 30 \text{ mAdc}, I_B = 0)$	60	-	Vdc	
ICER	Collector Cutoff Current (V _{CE} = 70 Vdc, R _{BE} = 100 Ohms)	-	1.0	mAdc	
I _{CEO}	Collector Cutoff Current (V _{CE} = 30 Vdc, I _B = 0)	-	0.7	mAdc	
I _{CEV}	Collector Cutoff Current (V _{CE} = 100 Vdc, V _{BE(off)} = 1.5 Vdc)	-	5.0	mAdc	
I _{EBO}	Emitter Cutoff Current ($V_{BE} = 7.0 \text{ Vdc}, I_C = 0$)	-	5.0	mAdc	

ON CHARACTERISTICS (Note 1)

h _{FE}	DC Current Gain ($I_C = 4.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$) ($I_C = 10 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$)	20 5.0	70 -	-
V _{CE(sat)}	Collector-Emitter Saturation Voltage ($I_C = 4.0 \text{ Adc}, I_B = 400 \text{ mAdc}$) ($I_C = 10 \text{ Adc}, I_B = 3.3 \text{ Adc}$)		1.1 3.0	Vdc
V _{BE(on)}	Base-Emitter On Voltage (I _C = 4.0 Adc, V _{CE} = 4.0 Vdc)	-	1.8	Vdc

SECOND BREAKDOWN

I _{s/b}	Second Breakdown Collector Current with Base Forward Biased	3.0	-	Adc
	(V _{CE} = 30 Vdc, t = 1.0 s; Nonrepetitive)			

DYNAMIC CHARACTERISTICS

fT	Current Gain — Bandwidth Product (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1.0 MHz)	2.5	-	MHz
h _{fe}	Small–Signal Current Gain (V _{CE} = 4.0 Vdc, I _C = 1.0 Adc, f = 1.0 kHz)	15	-	kHz

For additional design curves, refer to electrical characteristics curves of 2N3055.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

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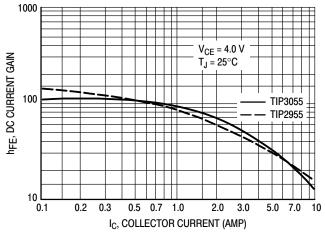


Figure 1. DC Current Gain

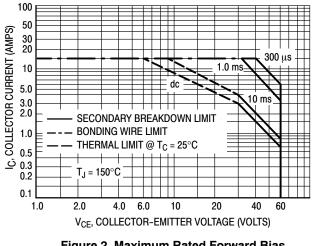


Figure 2. Maximum Rated Forward Bias Safe Operating Area

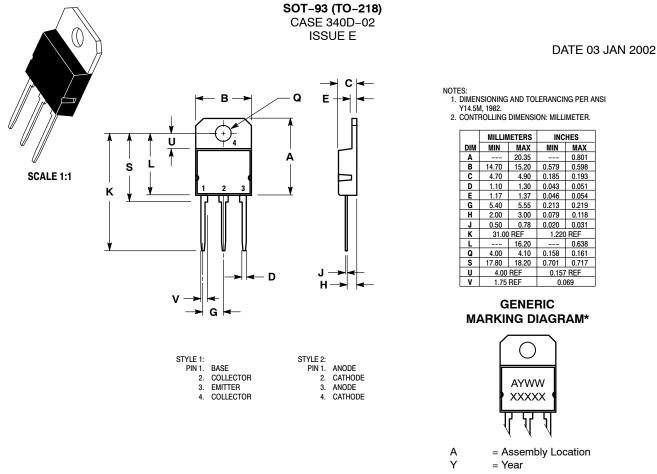
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated for temperature.

ORDERING INFORMATION

Device	Package	Shipping
TIP3055G	SOT-93 (TO-218) (Pb-Free)	30 Units / Rail
TIP2955G	SOT-93 (TO-218) (Pb-Free)	30 Units / Rail
TIP3055G	TO-247 (Pb-Free)	30 Units / Rail
TIP2955G	TO-247 (Pb-Free)	30 Units / Rail





- WW = Work Week
- XXXXX = Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOT-93 (TO-218)		PAGE 1 OF 1

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TO-247 CASE 340L ISSUE G G SCALE 1:1 Т В EATING -Ν Α 7 . ർറ ∲Ø0.63 (0.025)@|T|B@ Р Ý 2X F G ·H ЗХ D ♦ 0.25 (0.010) W Y AS

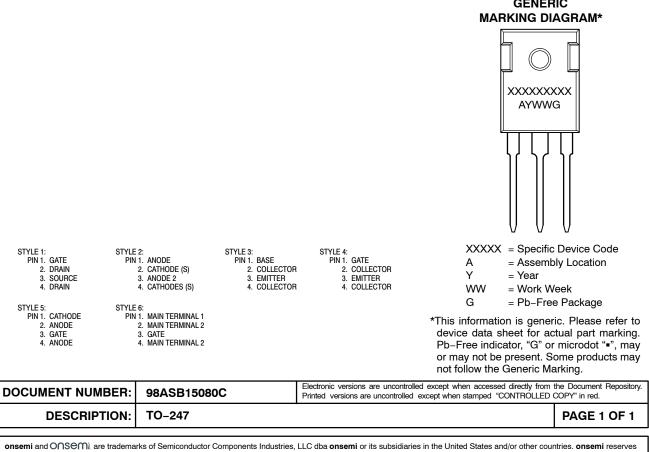
DATE 06 OCT 2021

NOTES

- DIMENSIONING AND TOLERANCING PER ASME 1. Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.		
A	20.32	21.08	0.800	0.830		
В	15.75	16.26	0.620	0.640		
С	4.70	5.30	0.185	0.209		
D	1.00	1.40	0.040	0.055		
E	1.90	2.60	0.075	0.102		
F	1.65	2.13	0.065	0.084		
G	5.45	BSC	0.215 BSC			
н	1.50	2.49	0.059	0.098		
J	0.40	0.80	0.016	0.031		
к	19.81	20.83	0.780	0.820		
L	5.40	6.20	0.212	0.244		
N	4.32	5.49	0.170	0.216		
Р		4.50		0.177		
Q	3.55	3.65	0.140	0.144		
U	6.15 BSC 0.242 H		BSC			
W	2.87	3.12	0.113	0.123		

GENERIC



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